



**R&T BiCMOS**

# Low Noise, Cryogenic Differential Amplifier

Prepared by: Bao TON

## DESCRIPTION

The RH6200 is an ultralow noise, rail-to-rail input and output unity-gain stable op amp that features  $0.95\text{nV}/\sqrt{\text{Hz}}$  noise voltage. This amplifier combines very low noise with a 165MHz gain bandwidth,  $50\text{V}/\mu\text{s}$  slew rate and is optimized for low voltage signal conditioning systems. A shutdown pin reduces supply current during standby conditions and thermal shutdown protects the part from overload conditions. The RH6200 maintains its pre-irradiation performance for supplies from 4.5V to 12.6V and is specified pre- and post-radiation at 5V and  $\pm 5\text{V}$ .

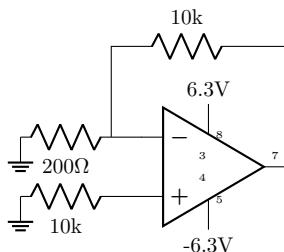
## ABSOLUTE MAXIMUM RATINGS

(Note 1)

Total Supply Voltage ( $V^+$ to $V^-$ )	12.6V
Input Current (Note 2)	$\pm 40\text{mA}$
Output Short-Circuit Duration (Note 3)	Indefinite
Pin Current While Exceeding Supplies (Note 4)	$\pm 30\text{mA}$
Operating Junction Temperature Range (Note 5)	-55°C to 125°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (Soldering, 10 sec)	300°C

All registered trademarks and trademarks are the property of their respective owners.

## BURN-IN CIRCUIT



RH6200M F01

## PACKAGE/ORDER INFORMATION

ORDER PART NUMBER	TOP VIEW
RH6200MW	 W PACKAGE 10-LEAD CERDIP

## TABLE 1: ELECTRICAL CHARACTERISTICS

Table 1: Table Fitted to Column Width

SYMBOL	PARAMETER	CONDITIONS	T <sub>A</sub> = 25°C			SUB-GROUP	-55°C ≤ T <sub>A</sub> ≤ 125°C			SUB-GROUP	UNITS
			S MIN	TYP	M AX		M IN	TYP	M AX		
<i>V<sub>OS</sub></i>	Input Offset Voltage	$V_S = 5V, 0V; V_{CM} = V^- \text{ to } V^+$ $V_S = \pm 5V; V_{CM} = V^- \text{ to } V^+$	0.6	2	1			4	2,3	mV	
	Voltage		2.5	6	1			9	2,3	mV	
<i>I<sub>B</sub></i>	Input Bias Current	$V_S = 5V, 0V; V_{CM} = V^+$ $V_S = 5V, 0V; V_{CM} = V^-$	8	18	1			20	2,3	μA	
			-50	-23	1	-100			2,3	μA	